TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX373F,TC74LVX373FW,TC74LVX373FT

Octal D-Type Latch with 3-State Output

The TC74LVX373F/FW/FT is a high-speed CMOS octal latch with 3-state output fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

This 8 bit D-type latch is controlled by a latch enable input (LE) and a output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high-impedance state.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

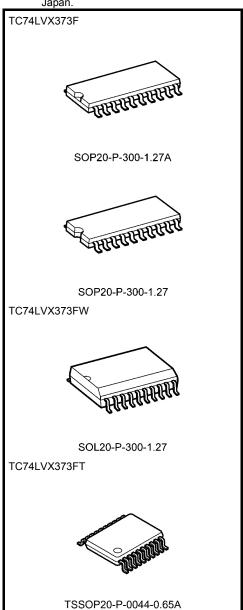
Features

- High-speed: $t_{pd} = 5.8 \text{ ns (typ.)} (V_{CC} = 3.3 \text{ V})$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Input voltage level: $V_{IL} = 0.8 \text{ V (max)} (V_{CC} = 3 \text{ V})$

$$V_{IH} = 2.0 \text{ V (min)} (V_{CC} = 3 \text{ V})$$

- · Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74HC373

Note: xxxFW (JEDEC SOP) is not available in



Weight

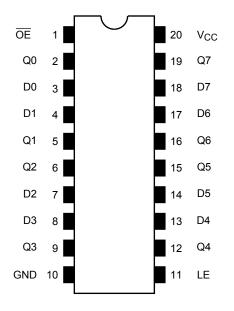
 SOP20-P-300-1.27A
 : 0.22 g (typ.)

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 : 0.22 g (typ.)

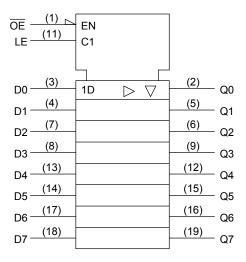
 SOL20-P-300-1.27
 : 0.46 g (typ.)

 TSSOP20-P-0044-0.65A
 : 0.08 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

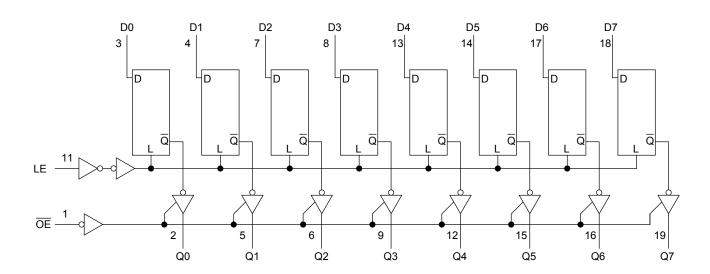
	Outputs		
ŌĒ	LE	D	Outputs
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V_{CC} + 0.5	٧
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	٧
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Condition			Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	Min	Тур.	Max	Min	Max			
					2.0	1.5	_	_	1.5	_	
	H-level	V_{IH}		_	3.0	2.0	_	_	2.0	_	
Input voltage						2.4	_	_	2.4	_	V
input voltage					2.0	_	_	0.5	_	0.5	V
	L-level V _{IL}	V_{IL}	_		3.0	_	_	0.8	_	0.8	
					_	_	0.8	_	0.8		
		V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9		
H-level	H-level			I _{OH} = -50 μA	3.0	2.9	3.0		2.9		
Output voltage	Output valtage			I _{OH} = -4 mA	3.0	2.58	_	_	2.48		V
Output voltage				I _{OL} = 50 μA	2.0		0	0.1		0.1	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	3.0		0	0.1		0.1	
				I _{OL} = 4 mA	3.0		_	0.36		0.44	
3-state output		loz	V _{IN} = V _{IH} or V _{IL}		3.6			±0.25		±2.5	μА
Off-state current		loz	$V_{OUT} = V_{CC}$ or GND		3.0			±0.23		±2.0	μΛ
Input leakage curre	ent	I _{IN}	V _{IN} = 5.5 V or GND		3.6	_	_	±0.1	_	±1.0	μΑ
Quiescent supply c	Quiescent supply current I_{CC} $V_{IN} = V_{CC}$ or GND		3.6	_	_	4.0	_	40.0	μΑ		

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = -40 to 85°C	Unit	
			V _{CC} (V)	Limit	Limit		
Minimum pulse width	hw an		2.7	6.5	7.5	ns	
(LE)	t _{W (H)}		3.3 ± 0.3	5.0	5.0	115	
Minimum set-up time	t _s		2.7	6.0	6.0	no	
		_	3.3 ± 0.3	4.0	4.0	ns	
Minimum hold time	t _h		2.7	1.0	1.0	no	
		_	3.3 ± 0.3	1.0	1.0	ns	



AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol Test Condition				Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
	t		2.7	15	_	7.5	14.5	1.0	17.5	ns
Propagation delay time	t _{pLH}		2.1	50	_	10.0	18.0	1.0	21.0	
(LE-Q)	t	_	3.3 ± 0.3	15		5.8	9.3	1.0	11.0	113
	t _{pHL}		3.5 ± 0.5	50		8.3	12.8	1.0	14.5	
	t		2.7	15		7.7	15.0	1.0	18.5	- ns
Propagation delay time	t _{pLH}	_	2.1	50		10.2	18.5	1.0	22.0	
(D-Q)	t _{pHL}		3.3 ± 0.3	15		6.0	9.7	1.0	11.5	
				50		8.5	13.2	1.0	15.0	
	t _{pZH}	$R_L = 1 \text{ k}\Omega$	2.7	15		7.7	15.0	1.0	18.5	ns
Output enable time				50		10.2	18.5	1.0	22.0	
Output enable time	t _{pZL}		3.3 ± 0.3	15		6.0	9.7	1.0	11.5	
				50		8.5	13.2	1.0	15.0	
Output disable time	t_{pLZ}	$R_{l} = 1 k\Omega$	2.7	50		9.8	18.0	1.0	21.0	ns
Output disable time	t_{pHZ}	IV[- 1 K22	3.3 ± 0.3	50		8.2	12.8	1.0	14.5	115
Output to output skew	t _{osLH}	(Note 1)	2.7	50	_	_	1.5	_	1.5	ns
Output to output skew	t_{osHL}	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	115
Input capacitance	C _{IN}			(Note 2)	_	4	10	_	10	pF
Output capacitance	C _{OUT}		_		_	6	_	_	_	pF
Power dissipation capacitance	C_{PD}			(Note 3)	_	27	_	_		pF

Note 1: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per latch)}$

And the total C_{PD} when n pcs. of Latch operate can be gained by the following equation:

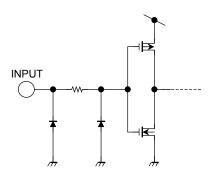
C_{PD} (total) = 14 + 13 · n



Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

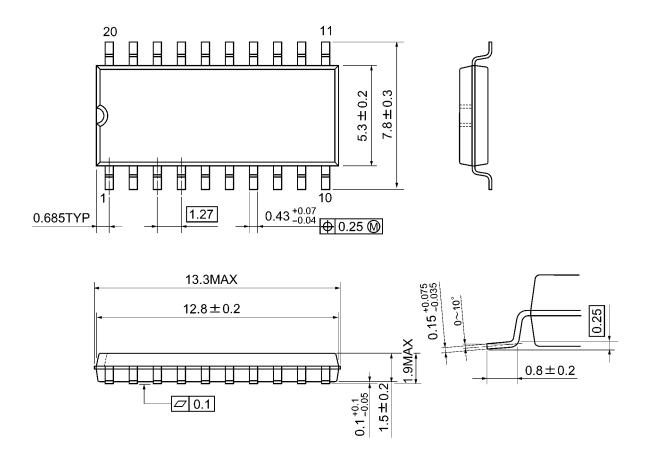
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	_	3.3	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	_	3.3	-0.5	-0.8	V
Minimum high level dynamic input voltage V_{IH}	V _{IHD}	_	3.3	_	2.0	V
Maximum low level dynamic input voltage V_{IL}	V _{ILD}	_	3.3		0.8	V

Input Equivalent Circuit



Package Dimensions

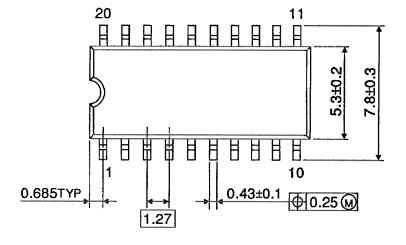
SOP20-P-300-1.27A Unit: mm

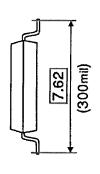


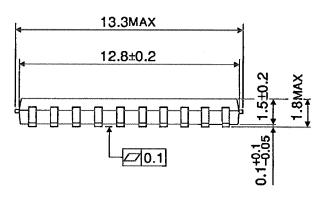
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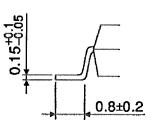
Package Dimensions

SOP20-P-300-1.27 Unit: mm







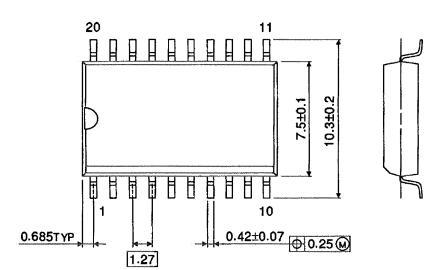


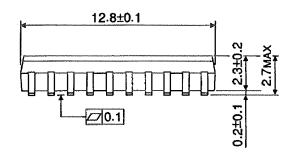
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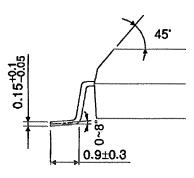
Unit: mm

Package Dimensions (Note)

SOL20-P-300-1.27







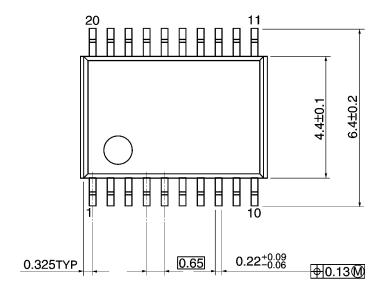
Note: This package is not available in Japan.

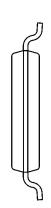
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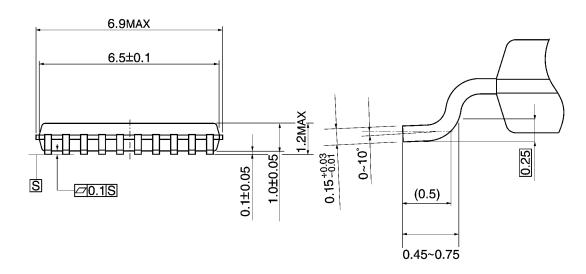
Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm







Weight: 0.08 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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